Single D-type flip-flop; positive-edge trigger Rev. 1 — 31 July 2012

Product data sheet

General description 1.

The 74LVC1G80-Q100 provides a single positive-edge triggered D-type flip-flop.

Information on the data input is transferred to the \overline{Q} output on the LOW-to-HIGH transition of the clock pulse. The input pin D must be stable one set-up time prior to the LOW-to-HIGH clock transition for predictable operation.

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device in a mixed 3.3 V and 5 V environment.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

Features and benefits 2.

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- Complies with JEDEC standard:
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- ± 24 mA output drive (V_{CC} = 3.0 V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options



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3. Ordering information

Table 1. Ordering information								
Type number	Package							
	Temperature range	Name	Description	Version				
74LVC1G80GW-Q100	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74LVC1G80GV-Q100	–40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753				

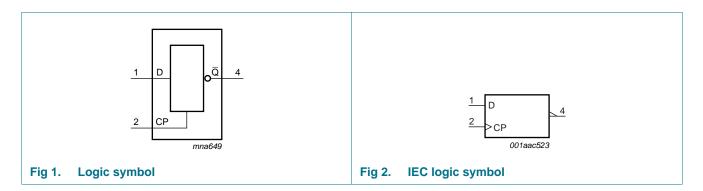
4. Marking

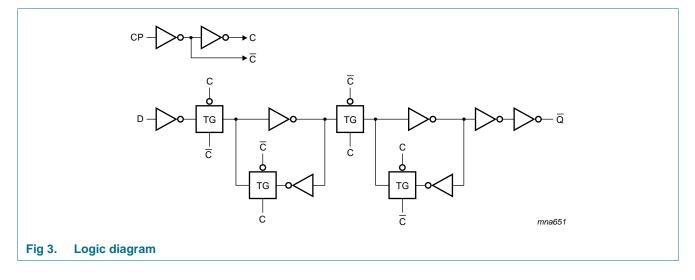
Table 2.	Marking	codes
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Type number	Marking ^[1]
74LVC1G80GW-Q100	VT
74LVC1G80GV-Q100	V80

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram

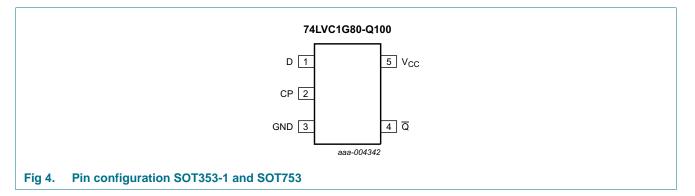




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6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
D	1	data input
CP	2	clock pulse input
GND	3	ground (0 V)
Q	4	data output
V _{CC}	5	supply voltage

7. Functional description

Table 4. Function table^[1]

Input		Output
СР	D	Q
\uparrow	L	Н
\uparrow	Н	L
L	Х	q

[1] H = HIGH voltage level;

L = LOW voltage level.

 \uparrow = LOW-to-HIGH CP transition;

X = don't care;

 \overline{q} = lower case letter indicates the state of referenced input, one set-up time prior to the LOW-to-HIGH CP transition.

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

					,
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+6.5	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+6.5	V
I _{OK}	output clamping current	$V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0 V	-	±50	mA
Vo	output voltage	Active mode	[1][2] -0.5	V _{CC} + 0.5	V
		Power-down mode	[1][2] -0.5	+6.5	V
lo	output current	$V_{O} = 0 V$ to V_{CC}	-	±50	mA
I _{CC}	supply current		-	100	mA
I _{GND}	ground current		-100	-	mA
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	[3] _	250	mW
T _{stg}	storage temperature		-65	+150	°C

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] When $V_{CC} = 0 V$ (Power-down mode), the output voltage can be 5.5 V in normal operation.

[3] For TSSOP5 and SC-74A packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		1.65	-	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	Active mode	0	-	V _{CC}	V
		$V_{CC} = 0 V$; Power-down mode	0	-	5.5	V
T _{amb}	ambient temperature		-40	-	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 1.65 V to 2.7 V	-	-	20	ns/V
		$V_{CC} = 2.7 \text{ V} \text{ to } 5.5 \text{ V}$	-	-	10	ns/V

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10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ <mark>[1]</mark>	Max	Unit
T _{amb} = -	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V_{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.7	-	-	V
		V_{CC} = 2.7 V to 3.6 V	2.0	-	-	V
		V_{CC} = 4.5 V to 5.5 V	$0.7\times V_{CC}$	-	-	V
VIL	LOW-level input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V_{CC} = 2.7 V to 3.6 V	-	-	0.8	V
		V_{CC} = 4.5 V to 5.5 V	-	-	$0.3\times V_{CC}$	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = $-100~\mu\text{A};~V_{CC}$ = 1.65 V to 5.5 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.2	-	-	V
		$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	-	-	V
		$I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.3	-	-	V
		$I_{O} = -32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.8	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 100 μ A; V _{CC} = 1.65 V to 5.5 V	-	-	0.1	V
		$I_0 = 4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.45	V
		I_{O} = 8 mA; V_{CC} = 2.3 V	-	-	0.3	V
		I_{O} = 12 mA; V_{CC} = 2.7 V	-	-	0.4	V
		$I_{O} = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.55	V
		$I_{O} = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.55	V
I _I	input leakage current	V_{I} = 5.5 V or GND; V_{CC} = 0 V to 5.5 V	-	±0.1	±5	μA
I _{OFF}	power-off leakage current	$V_{CC} = 0 \text{ V}; \text{ V}_{I} \text{ or } \text{V}_{O} = 5.5 \text{ V}$	-	±0.1	±10	μA
I _{CC}	supply current	$V_{I} = 5.5 V \text{ or GND};$ $V_{CC} = 1.65 V \text{ to } 5.5 V; I_{O} = 0 A$	-	0.1	10	μΑ
ΔI_{CC}	additional supply current	per pin; $V_{CC} = 2.3 \text{ V}$ to 5.5 V; $V_1 = V_{CC} - 0.6 \text{ V}$; $I_0 = 0 \text{ A}$	-	5	500	μA
CI	input capacitance	V_{CC} = 3.3 V; V_{I} = GND to V_{CC}	-	5	-	pF
T _{amb} = -	40 °C to +125 °C					
VIH	HIGH-level input voltage	V _{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.7	-	-	V
		$V_{CC} = 2.7 V \text{ to } 3.6 V$	2.0	-	-	V
		$V_{CC} = 4.5 V \text{ to } 5.5 V$	$0.7\times V_{CC}$	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 1.65 \text{ V}$ to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.8	V
		$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$	-	-	$0.3\times V_{CC}$	V
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At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).						
Symbol	Parameter	Conditions	Min	Typ <mark>[1]</mark>	Max	Unit
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = $-100~\mu\text{A};~V_{CC}$ = 1.65 V to 5.5 V	$V_{CC}-0.1$	-	-	V
		$I_0 = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	0.95	-	-	V
		$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.7	-	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	1.9	-	-	V
		$I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.0	-	-	V
		I_{O} = -32 mA; V_{CC} = 4.5 V	3.4	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 100 $\mu\text{A};V_{CC}$ = 1.65 V to 5.5 V	-	-	0.1	V
		I _O = 4 mA; V _{CC} = 1.65 V	-	-	0.70	V
		$I_0 = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.45	V
		$I_0 = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	-	0.60	V
		$I_0 = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.80	V
		$I_0 = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.80	V
I _I	input leakage current	$V_{\rm I}$ = 5.5 V or GND; $V_{\rm CC}$ = 0 V to 5.5 V	-	-	±100	μA
I _{OFF}	power-off leakage current	V_{CC} = 0 V; V_{I} or V_{O} = 5.5 V	-	-	±200	μA
I _{CC}	supply current	$V_{I} = 5.5 V \text{ or GND};$ $V_{CC} = 1.65 V \text{ to } 5.5 V; I_{O} = 0 A$	-	-	200	μA
ΔI_{CC}	additional supply current	per pin; V _{CC} = 2.3 V to 5.5 V; V _I = V _{CC} $- 0.6$ V; I _O = 0 A	-	-	5000	μA

Table 7. Static characteristics ... continued

[1] All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

11. Dynamic characteristics

Table 8. **Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 7.

Symbol	Parameter	Conditions		–40 °C to +85 °C			–40 °C to	o +125 ℃	Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max	
t _{pd}	propagation delay	CP to \overline{Q} ; see Figure 5	[2]						
		V_{CC} = 1.65 V to 1.95 V		1.0	3.4	9.9	1.0	13.0	ns
		V_{CC} = 2.3 V to 2.7 V		0.5	2.3	7.0	0.5	9.0	ns
		$V_{CC} = 2.7 V$		0.5	2.5	6.0	0.5	8.0	ns
		V_{CC} = 3.0 V to 3.6 V		0.9	2.4	5.0	0.9	6.5	ns
		V_{CC} = 4.5 V to 5.5 V		0.5	1.8	4.5	0.5	6.0	ns
t _{su}	set-up time	HIGH or LOW; D to CP; see <u>Figure 6</u>	<u>[3]</u>						
		V_{CC} = 1.65 V to 1.95 V		2.3	0.8	-	2.3	-	ns
		V_{CC} = 2.3 V to 2.7 V		1.5	0.6	-	1.5	-	ns
		$V_{CC} = 2.7 V$		1.5	0.5	-	1.5	-	ns
		V_{CC} = 3.0 V to 3.6 V		1.3	0.4	-	1.3	-	ns
		V_{CC} = 4.5 V to 5.5 V		1.1	0.5	-	1.1	-	ns

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Symbol	Parameter	Conditions		-40) °C to +85	°C	–40 °C to	o +125 ℃	Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max	
t _h	hold time	D to CP; see Figure 6					1		
		V_{CC} = 1.65 V to 1.95 V		0	-0.6	-	0	-	ns
		V_{CC} = 2.3 V to 2.7 V		0	-0.4	-	0	-	ns
		$V_{CC} = 2.7 V$		+0.5	-0.2	-	0.5	-	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		0.9	0.2	-	0.9	-	ns
		$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$		+0.5	-0.1	-	0.5	-	ns
t _W	pulse width	CP HIGH or LOW; see <u>Figure 6</u>							
		V_{CC} = 1.65 V to 1.95 V		3.0	1.1	-	3.0	-	ns
		V_{CC} = 2.3 V to 2.7 V		2.5	0.7	-	2.5	-	ns
		$V_{CC} = 2.7 V$		2.5	0.6	-	2.5	-	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.5	0.6	-	2.5	-	ns
		V_{CC} = 4.5 V to 5.5 V		2.0	0.5	-	2.0	-	ns
f _{max}	maximum	CP; see Figure 6							
	frequency	V_{CC} = 1.65 V to 1.95 V		160	300	-	160	-	MHz
		V_{CC} = 2.3 V to 2.7 V		160	350	-	160	-	MHz
		$V_{CC} = 2.7 V$		160	350	-	160	-	MHz
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		160	350	-	160	-	MHz
		V_{CC} = 4.5 V to 5.5 V		200	400	-	200	-	MHz
C _{PD}	power dissipation capacitance	$V_1 = GND$ to V_{CC} ; $V_{CC} = 3.3 V$	<u>[4]</u>	-	17	-	-	-	рF

Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V). For test circuit see <u>Figure 7</u>.

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] t_{su} is the same as $t_{su(H)}$ and $t_{su(L)}$.

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz;

 $f_0 = output frequency in MHz;$

 C_L = output load capacitance in pF;

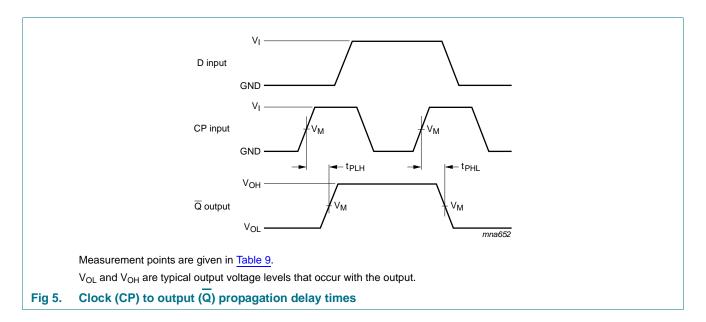
V_{CC} = supply voltage in V;

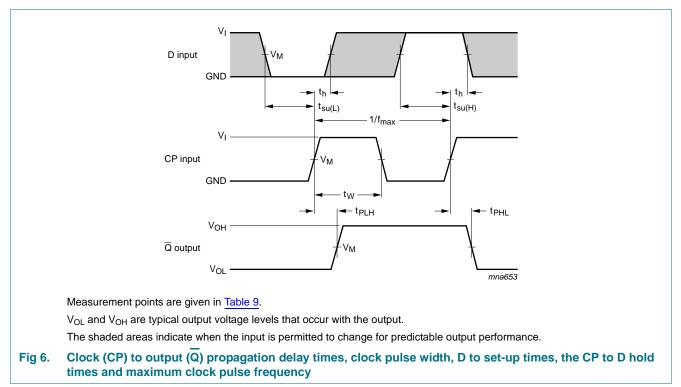
$$\begin{split} N &= number \mbox{ of inputs switching;} \\ \Sigma (C_L \times V_{CC}{}^2 \times f_o) &= sum \mbox{ of outputs.} \end{split}$$

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12. Waveforms





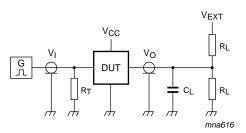
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Supply voltage	Input	Output			
V _{cc}	V _M	V _M			
1.65 V to 1.95 V	$0.5 imes V_{CC}$	$0.5 \times V_{CC}$			
2.3 V to 2.7 V	$0.5\times V_{CC}$	$0.5\times V_{CC}$			
2.7 V	1.5 V	1.5 V			
3.0 V to 3.6 V	1.5 V	1.5 V			
4.5 V to 5.5 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$			





Test data is given in Table 10.

Definitions for test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 7. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Input		Load		V _{EXT}
V _{cc}	VI	$t_r = t_f$	CL	RL	t _{PLH} , t _{PHL}
1.65 V to 1.95 V	V _{CC}	\leq 2.0 ns	30 pF	1 kΩ	open
2.3 V to 2.7 V	V _{CC}	\leq 2.0 ns	30 pF	500 Ω	open
2.7 V	2.7 V	\leq 2.5 ns	50 pF	500 Ω	open
3.0 V to 3.6 V	2.7 V	\leq 2.5 ns	50 pF	500 Ω	open
4.5 V to 5.5 V	V _{CC}	\leq 2.5 ns	50 pF	500 Ω	open

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13. Package outline

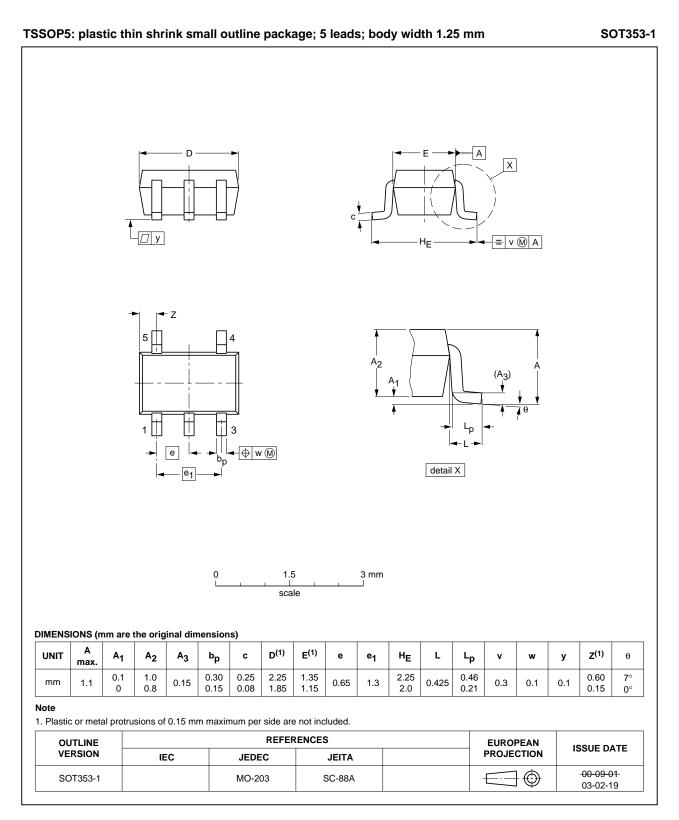


Fig 8. Package outline SOT353-1 (TSSOP5)

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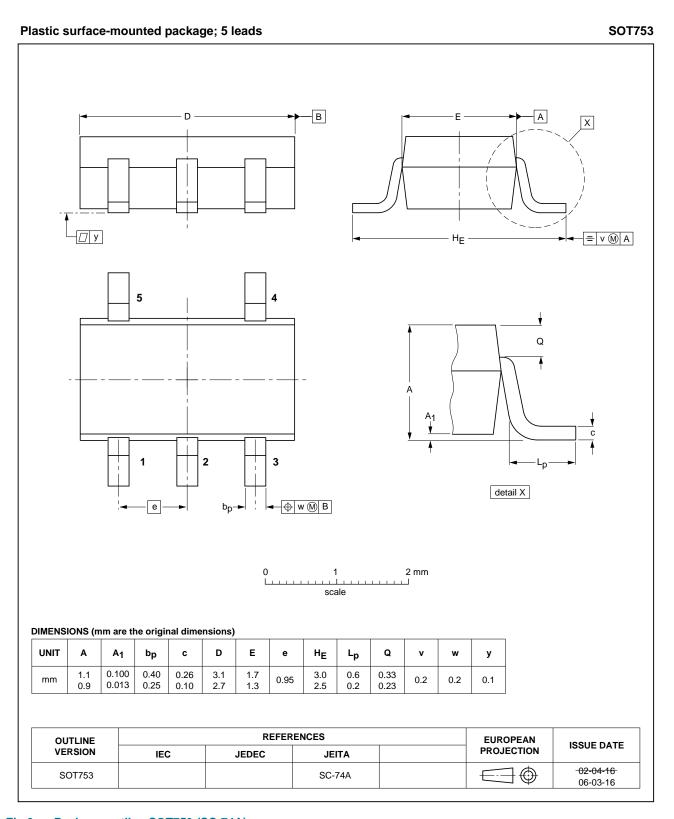


Fig 9. Package outline SOT753 (SC-74A)

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14. Abbreviations

Table 11. Abbreviations		
Acronym	Description	
CMOS	Complementary Metal Oxide Semiconductor	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
HBM	Human Body Model	
MM	Machine Model	
TTL	Transistor-Transistor Logic	
MIL	Military	

15. Revision history

Table 12. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1G80_Q100 v.1	20120731	Product data sheet	-	-

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16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Single D-type flip-flop; positive-edge trigger

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